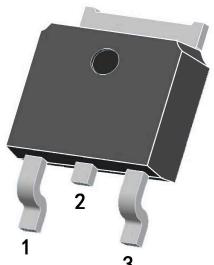


60V N-Channel Mosfet

**FEATURES**

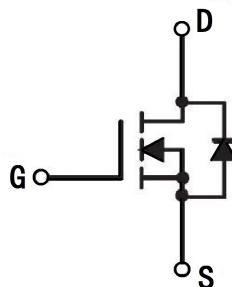
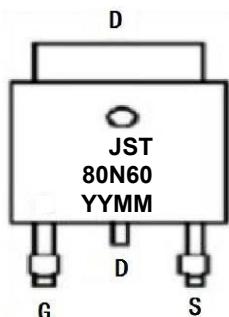
- $R_{DS(ON)} \leq 7\text{m}\Omega$  ( 5.3m $\Omega$  Typ.) @ $V_{GS}=10\text{V}$
- AEC Q101 qualified
- Green Product (RoHS compliant)
- 100% UIS TEST

**TO-252-2L**

1: G  
2: D  
3: S

**APPLICATIONS**

- Automotive Lighting
- Synchronous rectification
- PWM Application
- Power management

**N-CHANNEL MOSFET****MARKING**

**YYMM:**Date Code(year & month)

**Absolute Maximum Ratings ( $T_c=25^\circ\text{C}$  unless otherwise specified)**

Symbol	Parameter	Max.	Units
$V_{DSS}$	Drain-Source Voltage	60	V
$V_{GSS}$	Gate-Source Voltage	$\pm 20$	V
$I_D$	Continuous Drain Current @ $V_{GS}=10\text{V}$	$T_c = 25^\circ\text{C}$	A
		$T_c = 100^\circ\text{C}$	A
$I_{DM}$	Pulsed Drain Current <sup>note1</sup>	320	A
EAS	Single Pulsed Avalanche Energy <sup>note2</sup>	130	mJ
$P_D$	Power Dissipation	88	W
$R_{\theta JC}$	Thermal Resistance, Junction to Case	1.7	$^\circ\text{C}/\text{W}$
$T_J, T_{STG}$	Operating and Storage Temperature Range	-55 to +175	$^\circ\text{C}$

**Electrical Characteristics ( $T_J=25^\circ\text{C}$  unless otherwise specified)**

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
<b>Off Characteristic</b>						
$V_{(\text{BR})\text{DSS}}$	Drain-Source Breakdown Voltage	$V_{GS}=0\text{V}, I_D=250\mu\text{A}$	60	-	-	V
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{DS}=60\text{V}, V_{GS}=0\text{V},$	-	-	1.0	$\mu\text{A}$
$I_{GSS}$	Gate to Body Leakage Current	$V_{DS}=0\text{V}, V_{GS}=\pm 20\text{V}$	-	-	$\pm 100$	nA
<b>On Characteristics</b>						
$V_{GS(\text{th})}$	Gate Threshold Voltage	$V_{DS}=V_{GS}, I_D=250\mu\text{A}$	2	3	4	V
$R_{DS(\text{on})}$	Static Drain-Source on-Resistance note3	$V_{GS}=10\text{V}, I_D=30\text{A}$	-	5.3	7	$\text{m}\Omega$
<b>Dynamic Characteristics</b> note4						
$C_{iss}$	Input Capacitance	$V_{DS}=30\text{V}, V_{GS}=0\text{V}, f=1.0\text{MHz}$	-	4136	-	pF
$C_{oss}$	Output Capacitance		-	286	-	pF
$C_{rss}$	Reverse Transfer Capacitance		-	257	-	pF
$Q_g$	Total Gate Charge	$V_{DS}=30\text{V}, I_D=30\text{A}, V_{GS}=10\text{V}$	-	90	-	nC
$Q_{gs}$	Gate-Source Charge		-	9	-	nC
$Q_{gd}$	Gate-Drain("Miller") Charge		-	18	-	nC
<b>Switching Characteristics</b> note4						
$t_{d(on)}$	Turn-on Delay Time	$V_{DS}=30\text{V}, I_D=30\text{A}, R_G=1.8\Omega, V_{GS}=10\text{V}$	-	9	-	ns
$t_r$	Turn-on Rise Time		-	7	-	ns
$t_{d(off)}$	Turn-off Delay Time		-	40	-	ns
$t_f$	Turn-off Fall Time		-	15	-	ns
<b>Drain-Source Diode Characteristics and Maximum Ratings</b>						
$V_{SD}$	Drain to Source Diode Forward Voltage	$V_{GS}=0\text{V}, I_S=30\text{A}$	-	-	1.2	V
$trr$	Body Diode Reverse Recovery Time	$I_F=30\text{A}, dI/dt=100\text{A}/\mu\text{s}$	-	33	-	ns
$Qrr$	Body Diode Reverse Recovery Charge		-	46	-	nC

Notes: 1. Repetitive Rating: Pulse Width Limited by Maximum Junction Temperature

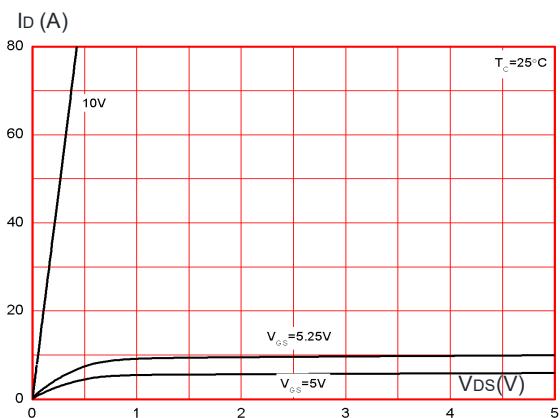
2. EAS condition :  $T_J=25^\circ\text{C}, V_{DD}=30\text{V}, V_G=10\text{V}, L=0.5\text{mH}, R_G=25\Omega, I_{AS}=22.8\text{A}$

3. Pulse Test: Pulse Width $\leq 300\mu\text{s}$ , Duty Cycle $\leq 0.5\%$

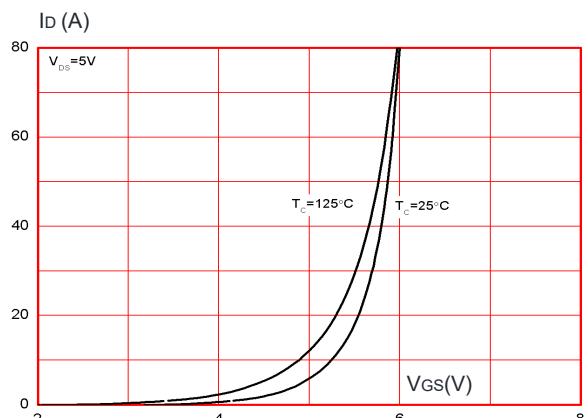
4. Guaranteed by design, not subject to production testing

## TYPICAL PERFORMANCE CHARACTERISTICS

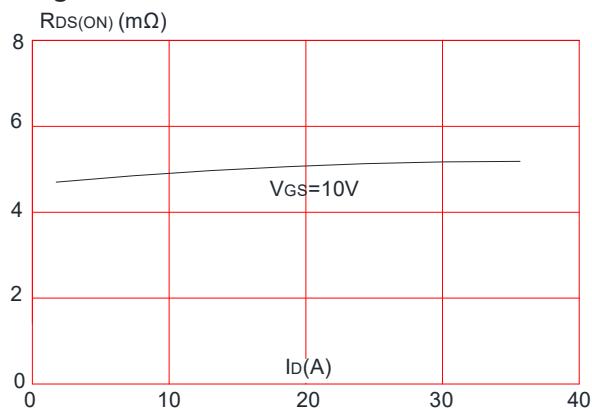
**Figure 1:** Output Characteristics



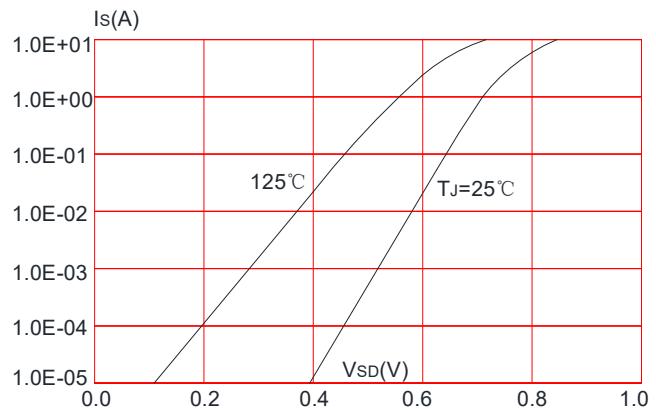
**Figure 2:** Typical Transfer Characteristics



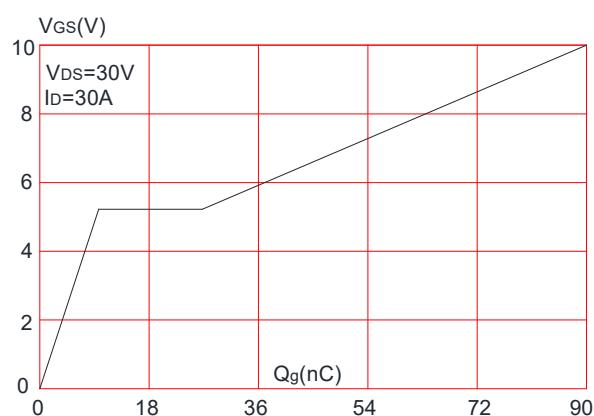
**Figure 3:** On-resistance vs. Drain Current



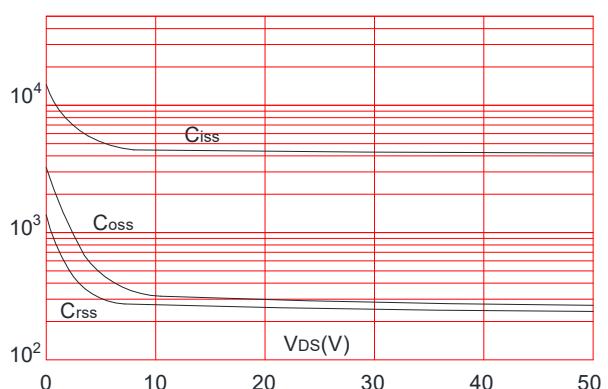
**Figure 4:** Body Diode Characteristics



**Figure 5:** Gate Charge Characteristics

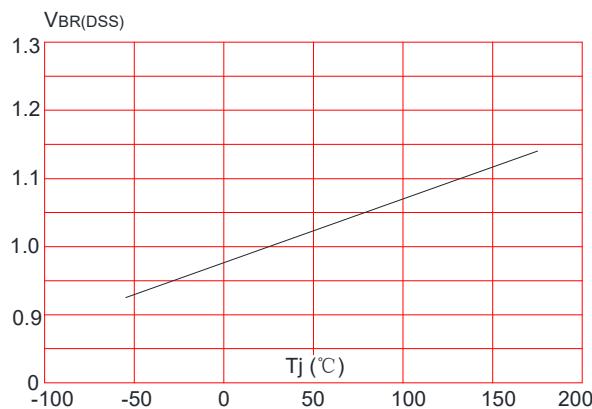


**Figure 6:** Capacitance Characteristics

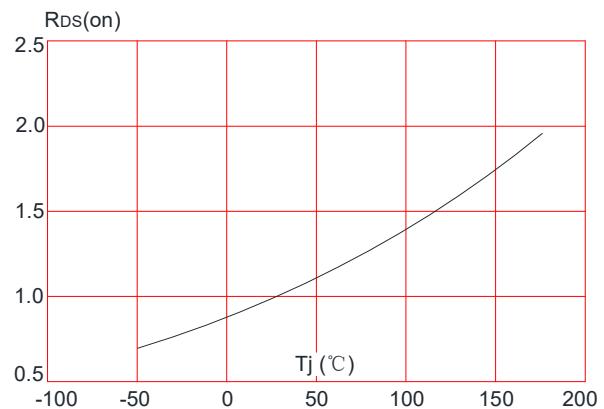


## TYPICAL PERFORMANCE CHARACTERISTICS (cont.)

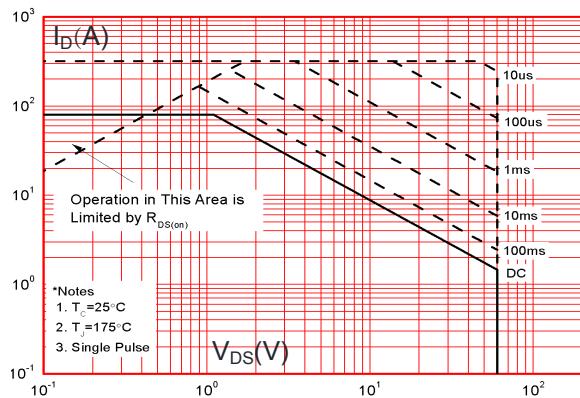
**Figure 7:** Normalized Breakdown Voltage vs. Junction Temperature



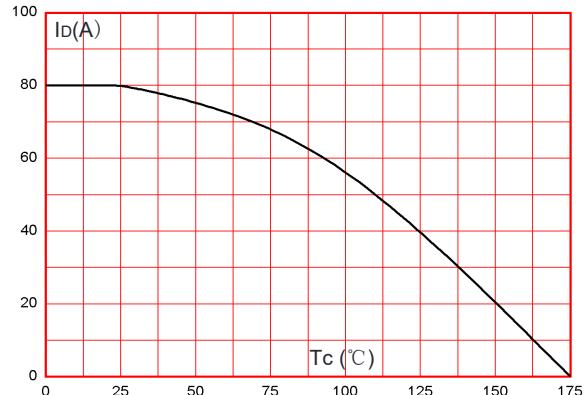
**Figure 8:** Normalized on Resistance vs. Junction Temperature



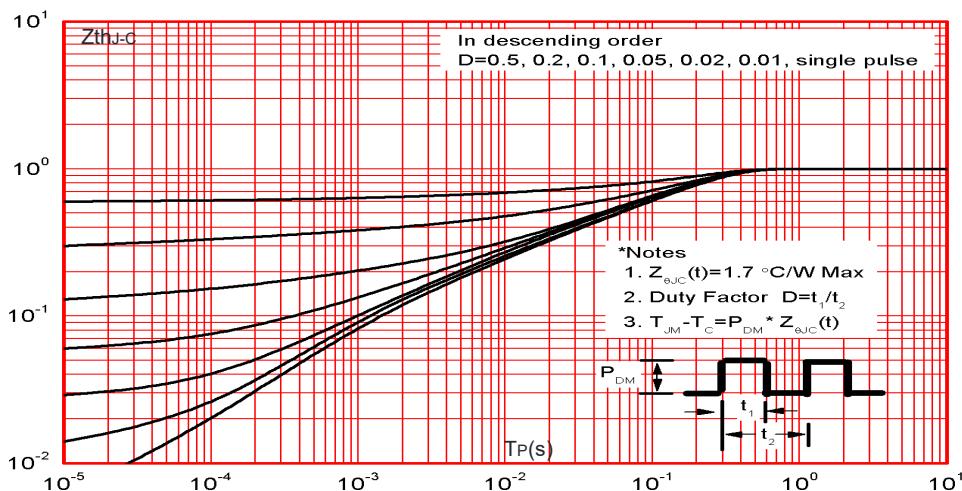
**Figure 9:** Maximum Safe Operating Area



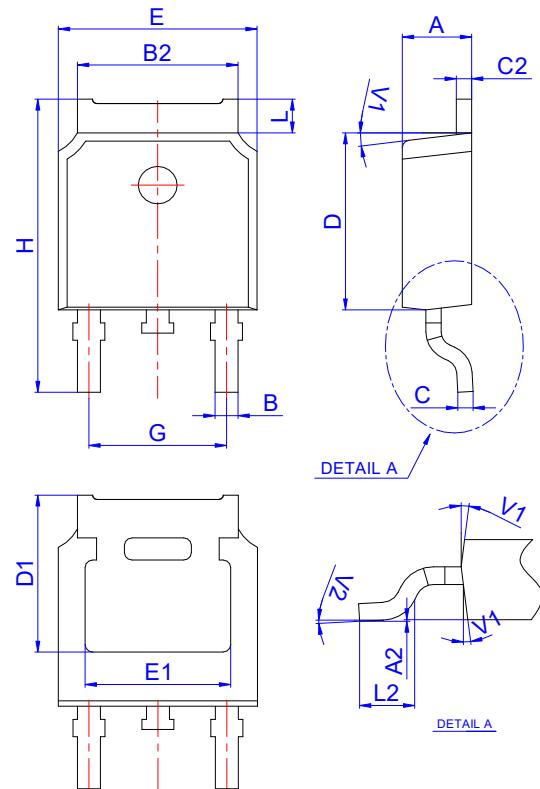
**Figure 10:** Maximum Continuous Drain Current vs. Case Temperature



**Figure 11:** Maximum Effective Transient Thermal Impedance, Junction-to-Case



## TO-252-2L PACKAGE OUTLINE DRAWING



Symbols	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.10		2.50	0.083		0.098
A2	0		0.10	0		0.004
B	0.66		0.86	0.026		0.034
B2	5.18		5.48	0.202		0.216
C	0.40		0.60	0.016		0.024
C2	0.44		0.58	0.017		0.023
D	5.90		6.30	0.232		0.248
D1	5.30REF			0.209REF		
E	6.40		6.80	0.252		0.268
E1	4.63			0.182		
G	4.47		4.67	0.176		0.184
H	9.50		10.70	0.374		0.421
L	1.09		1.21	0.043		0.048
L2	1.35		1.65	0.053		0.065
V1		7°			7°	
V2	0°		6°	0°		6°